Docket: 740819-720

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re New Patent Application of		)	
Akihiko ISHIBASHI et al.		)	
Japanese Priority Application 2000-386624		) Attn:	Applications
Japanese Priority Date: December 20, 2000		)	Branch
For:	METHOD FOR FABRICATING	)	
	SEMICONDUCTOR, METHOD FOR	)	
	FABRICATING SEMICONDUCTOR	)	
	SUBSTRATE, AND SEMICONDUCTOR	)	
	LIGHT EMITTING DEVICE	) Date:	December 18, 2001

## **INFORMATION DISCLOSURE STATEMENT**

Honorable Commissioner for Patents and Trademarks Washington, D.C. 20231

Sir:

In accordance with the provisions of 37 C.F.R. 1.56 and 37 C.F.R. 1.97-1.99, it is requested that the reference listed on the attached Form PTO-1449 be made of record in the above-identified application.

A copy of this reference is submitted herewith in accordance with 37 C.F.R. 1.98(a).

Respectfully submitted,

Eric J. Robinson

Registration No. 38,285

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